



## -40V/-13A P-Channel Advanced Power MOSFET

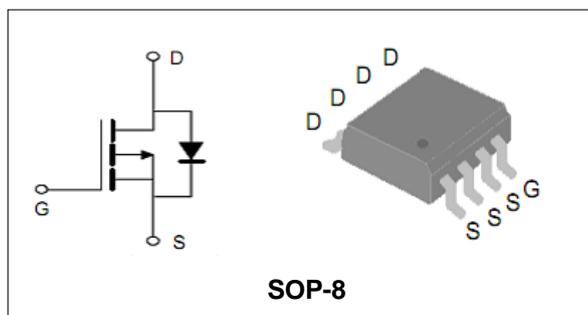
### Features

- Improved dv/dt Capability, High Ruggedness.
- Maximum Junction Temperature Range (150°C)

BVDSS	-40	V
ID	-13	A
RDSON@VGS=-10V	12	mΩ
RDSON@VGS=-4.5V	15	mΩ

### Applications

- PWM applications
- Load switch
- Power management



### Order Information

Product	Package	Marking	Reel Size	Reel	Carton
PTS40P13	SOP-8	PTS40P13	13inch	3000PCS	48000PCS

### Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit	
<b>Common Ratings (TC=25°C Unless Otherwise Noted)</b>				
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	-40	V	
$V_{GS}$	Gate-Source Voltage	±20	V	
$T_J$	Maximum Junction Temperature	150	°C	
$T_{STG}$	Storage Temperature Range	-55 to 150	°C	
$I_S$	Diode Continuous Forward Current	$T_A = 25^\circ C$	-13	A
<b>Mounted on Large Heat Sink</b>				
$I_{DM}$	Pulse Drain Current Tested (Silicon Limit) (Note1)	$T_A = 25^\circ C$	-52	A
$I_D$	Continuous Drain current	$T_A = 25^\circ C$	-13	A
$P_D$	Maximum Power Dissipation	$T_A = 25^\circ C$	2.5	W
$R_{\theta JA}$	Thermal Resistance Junction-to-Ambient (Note2)		50	°C/W

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Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
<b>Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
V <sub>(BR)DSS</sub>	Drain- Source Breakdown Voltage	VGS=0V ID=-250μA	-40	--	--	V
I <sub>DSS</sub>	Zero Gate Voltage Drain current	VDS=-40V,VGS=0V	--	--	1	μA
I <sub>GSS</sub>	Gate-Body Leakage Current	VGS=±20V,VDS=0V	--	--	±100	nA
V <sub>GS(TH)</sub>	Gate Threshold Voltage	VDS=VGS,ID=-250μA	-1.1	--	-2.1	V
R <sub>DS(ON)</sub>	Drain-Source On-State Resistance (Note3)	VGS=-10V, ID=-10A	--	12	14	mΩ
		VGS=-4.5V, ID=-8A	--	15	19	mΩ
<b>Dynamic Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated) (Note4)</b>						
C <sub>iss</sub>	Input Capacitance	VDS= -20V, VGS=0V, F=1MHz	--	3290	--	pF
C <sub>oss</sub>	Output Capacitance		--	258	--	pF
C <sub>rss</sub>	Reverse Transfer Capacitance		--	6	--	pF
Q <sub>g</sub>	Total Gate Charge	VDS= -20V, ID= -8A, VGS= -10V	--	47	--	nC
Q <sub>gs</sub>	Gate-Source Charge		--	7	--	nC
Q <sub>gd</sub>	Gate-Drain Charge		--	14	--	nC
<b>Switching Characteristics (Note4)</b>						
t <sub>d(on)</sub>	Turn-on Delay Time	VDD=-10V, ID=-8A, RG=6Ω, VGS=-10V	--	13	--	nS
t <sub>r</sub>	Turn-on Rise Time		--	88	--	nS
t <sub>d(off)</sub>	Turn-off Delay Time		--	104	--	nS
t <sub>f</sub>	Turn-off Fall Time		--	41	--	nS
<b>Source- Drain Diode Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
V <sub>SD</sub>	Forward on voltage (Note3)	IS=-8A,VGS=0V	--	--	-1.2	V

Note:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board, t ≤ 10 sec
3. Pulse Test: pulse width ≤ 300 us, duty cycle ≤ 2%.
4. Guaranteed by design, not subject to production testing.



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Typical Characteristics

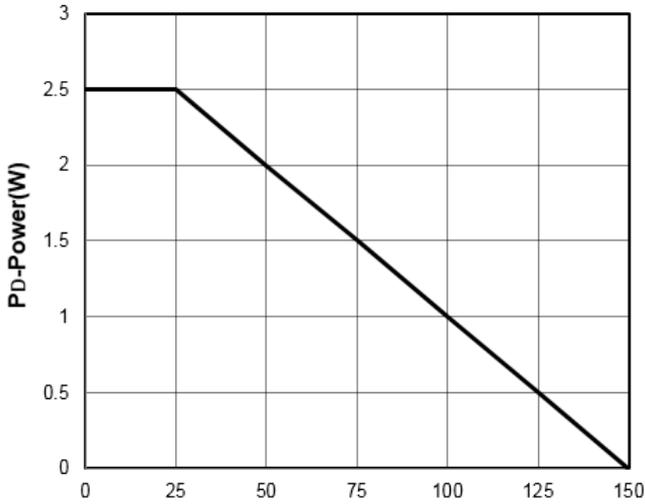


Figure1: T<sub>J</sub> Junction Temperature (°C)

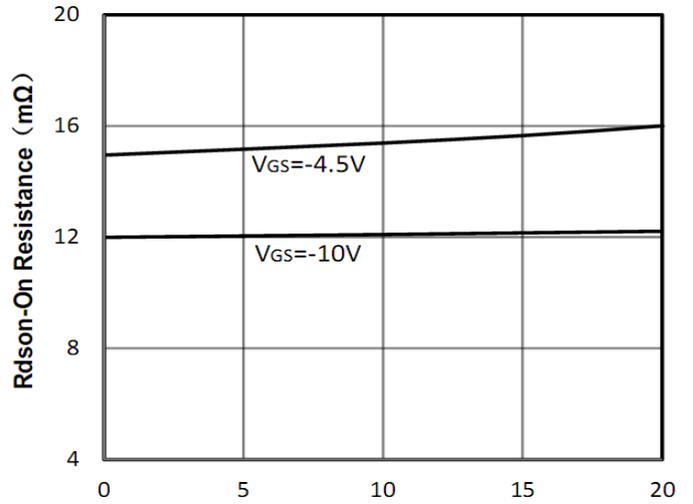


Figure2: -I<sub>D</sub> Drain Current (A)

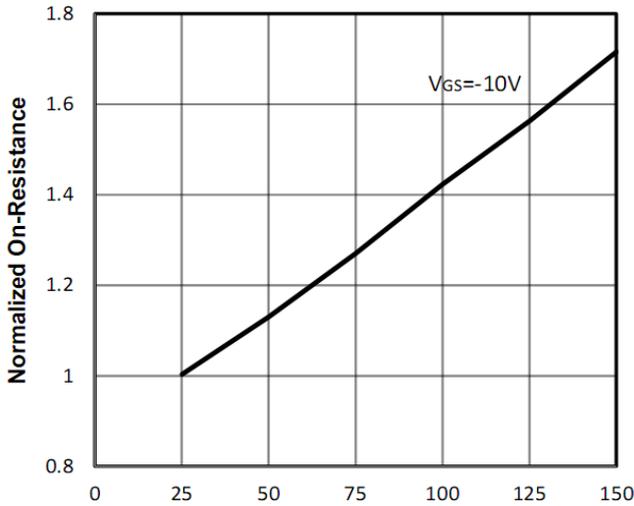


Figure3: T<sub>J</sub> Junction Temperature (°C)

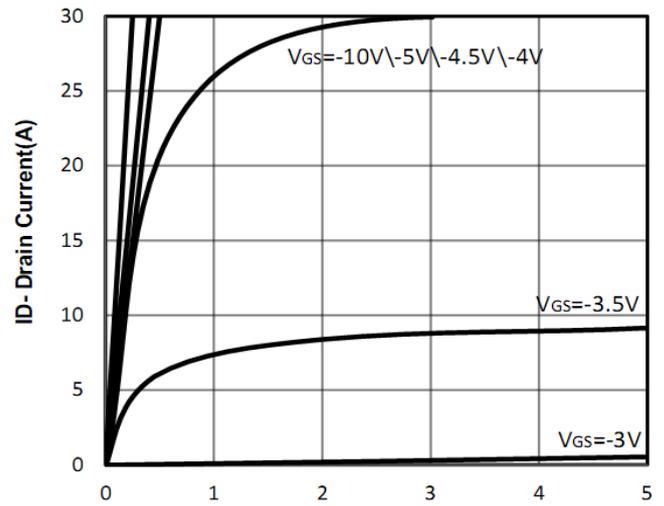


Figure4: -V<sub>DS</sub> Drain-Source Voltage (V)

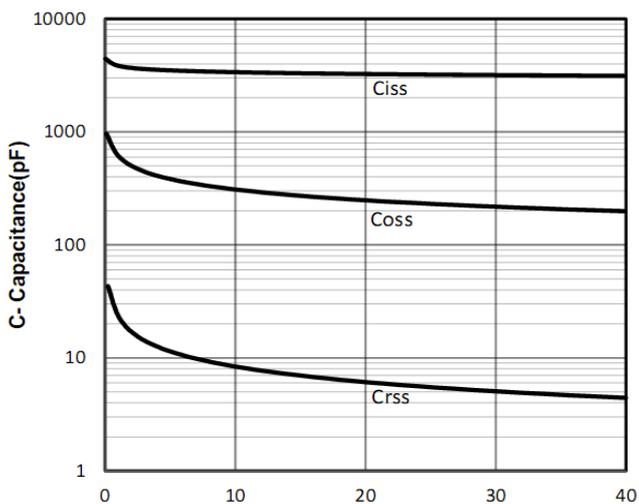


Figure5: -V<sub>DS</sub> Drain-Source Voltage (V)

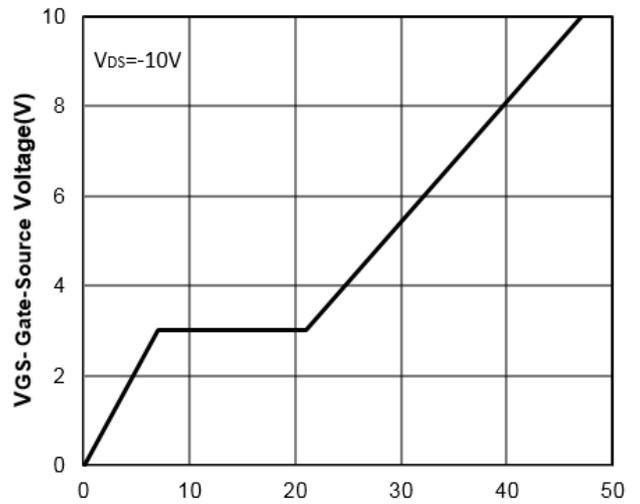


Figure6: Q<sub>g</sub> Gate Charge (nC)



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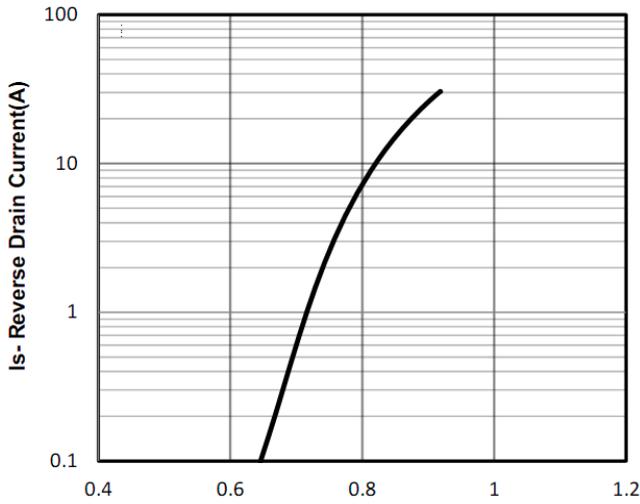


Figure7: -Vsd Source-Drain Voltage (V)

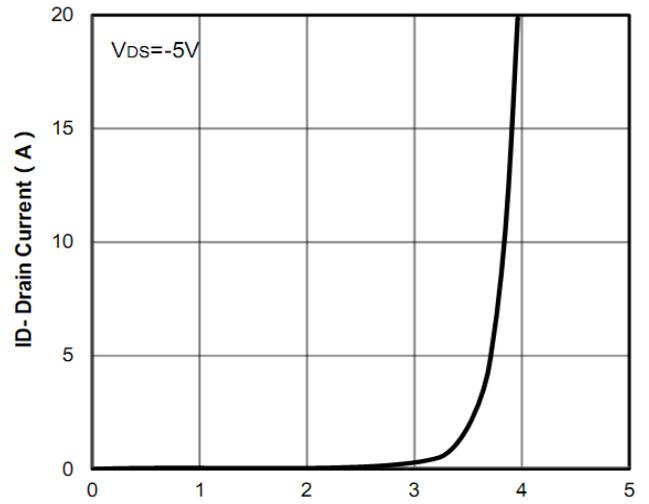


Figure8: -Vgs Gate-Source Voltage (V)

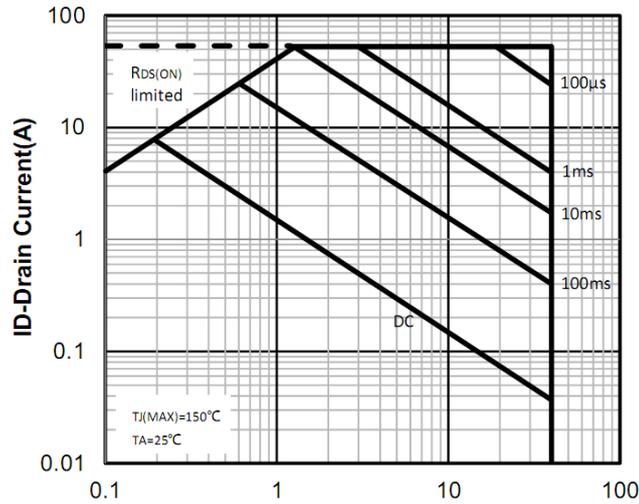


Figure9: -VDS Drain -Source Voltage (V)

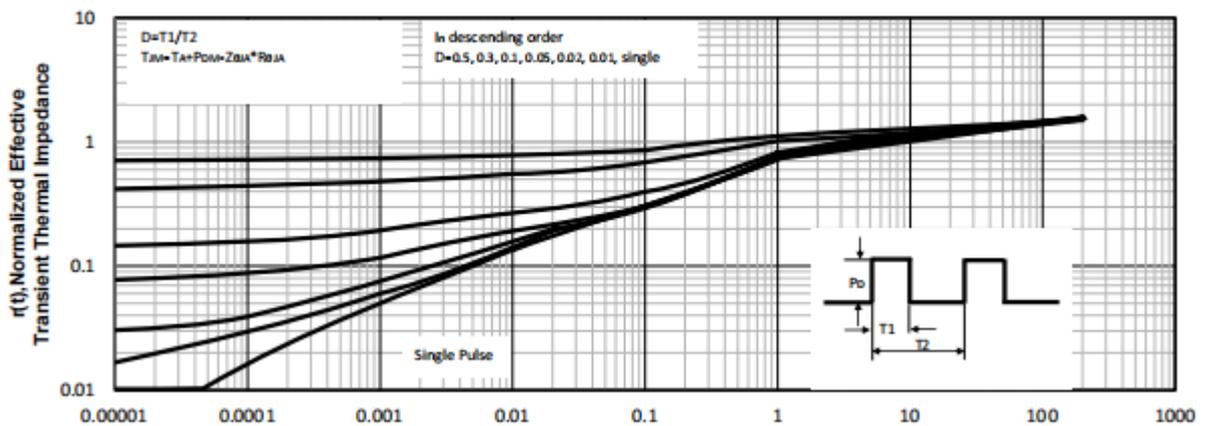


Figure10: Square Wave Pulse Duration (sec)

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Test Circuit and Waveform:

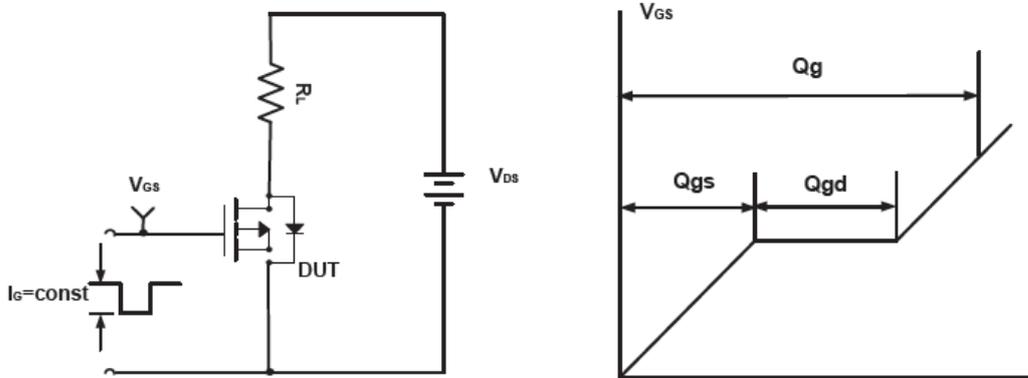


Figure A Gate Charge Test Circuit & Waveforms

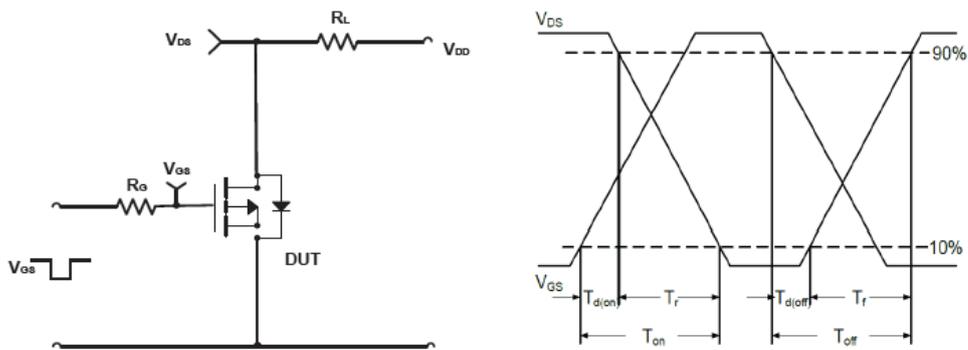
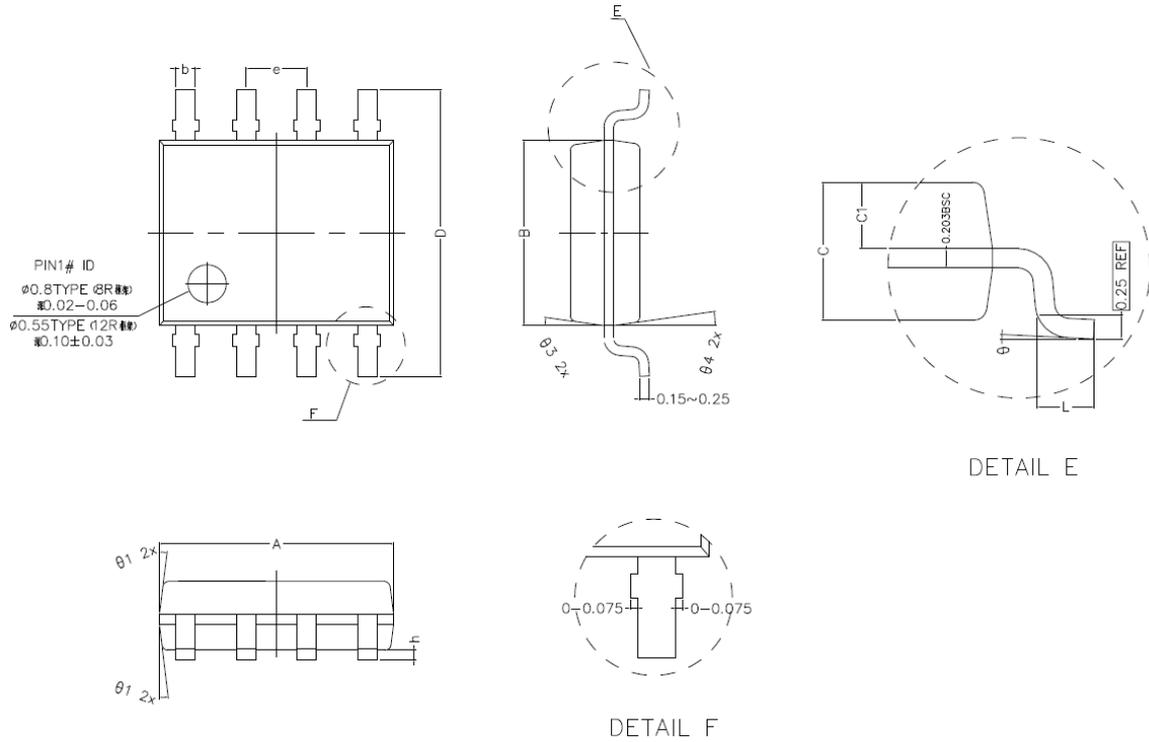


Figure B Switching Test Circuit & Waveforms

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### SOP-8 Package Outline Dimensions (Units: mm)



COMMON DIMENSIONS (UNITS OF MEASURE IS mm)			
	MIN	NORMAL	MAX
A	4.800	4.900	5.000
B	3.800	3.900	4.000
C	1.350	1.450	1.550
C1	0.650	0.700	0.750
D	5.900	6.100	6.300
L	0.500	0.600	0.700
b	0.350	0.400	0.450
h	0.050	0.150	0.250
e	1.270TYPE		
$\theta_1$	7° TYPE(8R)		12° TYPE(12R)
$\theta_2$	7° TYPE(8R)		10° TYPE(12R)
$\theta_3$	8° TYPE(8R)		12° TYPE(12R)
$\theta_4$	8° TYPE(8R)		10° TYPE(12R)
$\theta$	0° ~ 8°		